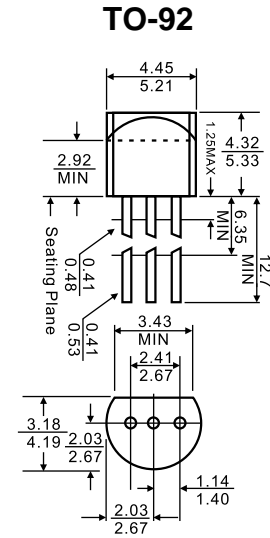




1. EMITTER
2. COLLECTOR
3. BASE

Features

- ✧ **Excellent h_{FE} Linearity**
 : $h_{FE}(2)=100(\text{Typ})$ at $V_{CE}=6V, I_C=150\text{mA}$
 : $h_{FE}(I_C=0.1\text{mA})/h_{FE}(I_C=2\text{mA})=0.95(\text{Typ})$.
- ✧ **Low Noise: $NF=10\text{dB}(\text{Typ})$. At $f=1\text{KHz}$.**



Dimensions in inches and (millimeters)

MAXIMUM RATINGS ($T_A=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	60	V
V_{CEO}	Collector-Emitter Voltage	50	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current -Continuous	150	mA
P_C	Collector power dissipation	625	mW
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{stg}	Storage Temperature	-55-150	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS ($T_{amb}=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=100\mu\text{A}, I_E=0$	60			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=10\text{mA}, I_B=0$	50			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=10\mu\text{A}, I_C=0$	5			V
Collector cut-off current	I_{CBO}	$V_{CB}=60\text{V}, I_E=0$			0.1	μA
Emitter cut-off current	I_{EBO}	$V_{EB}=5\text{V}, I_C=0$			0.1	μA
DC current gain	h_{FE}	$V_{CE}=6\text{V}, I_C=2\text{mA}$	70		700	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=100\text{mA}, I_B=10\text{mA}$		0.1	0.25	V
Transition frequency	f_T	$V_{CE}=10\text{V}, I_C=1\text{mA}$	80			MHz
Collector output capacitance	C_{ob}	$V_{CB}=10\text{V}, I_E=0, f=1\text{MHz}$			3.5	pF
Noise figure	NF	$V_{CE}=6\text{V}, I_C=0.1\text{mA}, f=1\text{KHz}, R_g=10\text{K}\Omega$			10	dB

CLASSIFICATION OF h_{FE}

Rank	O	Y	G	L
Range	70-140	120-240	200-400	300-700

Typical Characteristics

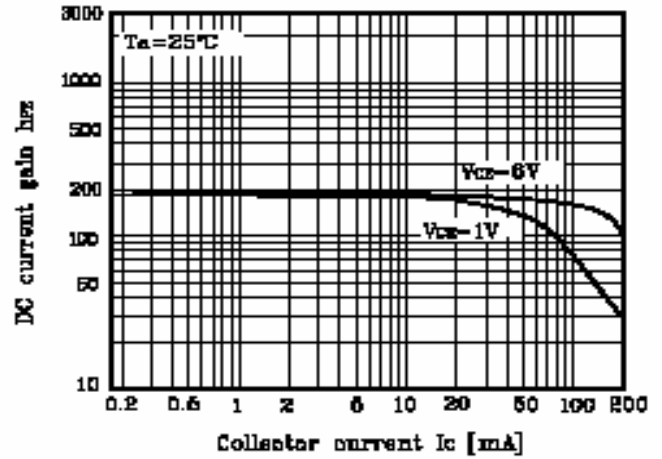
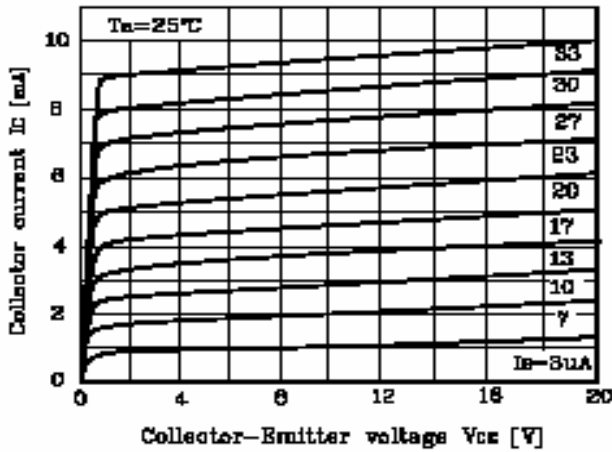
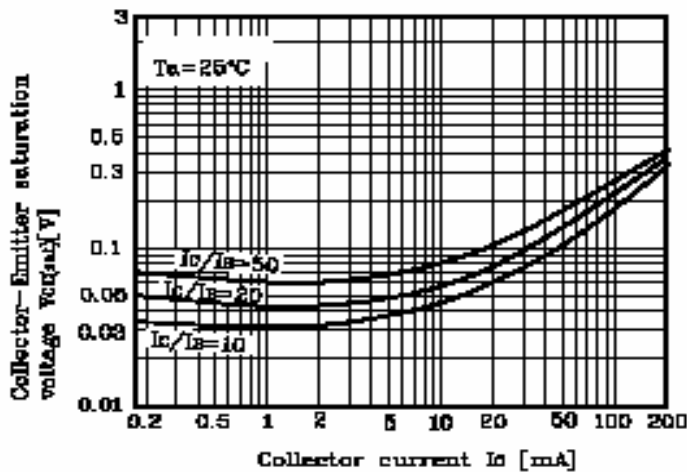


Fig. 5 $V_{ce(sat)} - I_c$



Package	Box	Box Size(mm)	Carton	Carton Size(mm)
TO-92	2000pcs	333×162×43	20,000pcs	350×340×250